# imall

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# ISOTOP<sup>®</sup> Buck chopper NPT IGBT

## $V_{CES} = 600V$ $I_{C} = 60A$ @ Tc = 95°C

# 



#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### Features

- Non Punch Through (NPT) THUNDERBOLT IGBT
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 100 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- ISOTOP<sup>®</sup> Package (SOT-227)
- Very low stray inductance
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive  $T_C$  of  $V_{CEsat}$
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage			600	V
I <sub>C1</sub>	Continuous Collector Current		$T_C = 25^{\circ}C$	93	
I <sub>C2</sub>			$T_C = 95^{\circ}C$	60	Α
I <sub>CM</sub>	Pulsed Collector Current		$T_C = 25^{\circ}C$	360	
V <sub>GE</sub>	Gate – Emitter Voltage	±20	V		
PD	Maximum Power Dissipation		$T_C = 25^{\circ}C$	378	W
$I_{LM}$	RBSOA clamped Inductive load Current $R_G=11\Omega$		$T_C = 25^{\circ}C$	360	А
IF <sub>AV</sub>	Maximum Average Forward Current	Duty cycle=0.5	$T_C = 80^{\circ}C$	30	А
IF <sub>RMS</sub>	RMS Forward Current (Square wave, 50% duty)			39	Λ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



## All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
<b>BV</b> <sub>CES</sub>	Collector - Emitter Breakdown Voltage	$V_{GE} = 0V, I_C = 0.5mA$		600			V
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			80	۸
		$V_{CE} = 600V$ $T_j = 125^{\circ}C$			2000	μA	
V <sub>CE(on)</sub>	Collector Emitter on Voltage	$V_{GE} = 15V$ $T_j = 25^{\circ}C$		2.0	2.5	V	
	Conector Ennitier on Voltage	$I_C = 60A$	$T_{j} = 125^{\circ}C$			2.8	v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 500 \mu A$		3	4	5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±100	nA

## **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		3125	3590	
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$		310	450	pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		180	310	
Qg	Total gate Charge	$V_{GS} = 15V$		257	410	
Q <sub>ge</sub>	Gate – Emitter Charge	$V_{Bus} = 300V$		19	30	nC
Q <sub>gc</sub>	Gate – Collector Charge	$I_C = 60A$		120	180	
T <sub>d(on)</sub>	Turn-on Delay Time	Resistive Switching (25°C)		20	40	
Tr	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 300V$		95	190	nc
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 60 \text{A}$		315	470	ns
T <sub>f</sub>	Fall Time	$R_G = 5\Omega$		245	490	
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		26	50	
T <sub>r</sub>	Rise Time	$V_{GE} = 15V$		63	125	20
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 60A$		395	590	ns
T <sub>f</sub>	Fall Time	$R_{\rm G} = 5\Omega$		68	140	
E <sub>ts</sub>	Total switching Losses			3.4	7	mJ
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = 15V$ $V_{Bus} = 400V$ $I_C = 60A$		25	50	
T <sub>r</sub>	Rise Time			59	120	ns
T <sub>d(off)</sub>	Turn-off Delay Time			430	650	115
T <sub>f</sub>	Fall Time	$R_{G} = 5\Omega$		65	130	
Eon	Turn-on Switching Energy	0		1.6	3.2	
E <sub>off</sub>	Turn-off Switching Energy			2.4	4.8	mJ
E <sub>ts</sub>	Total switching Losses			4.0	8.0	



#### Chopper ciode ratings and characteristics

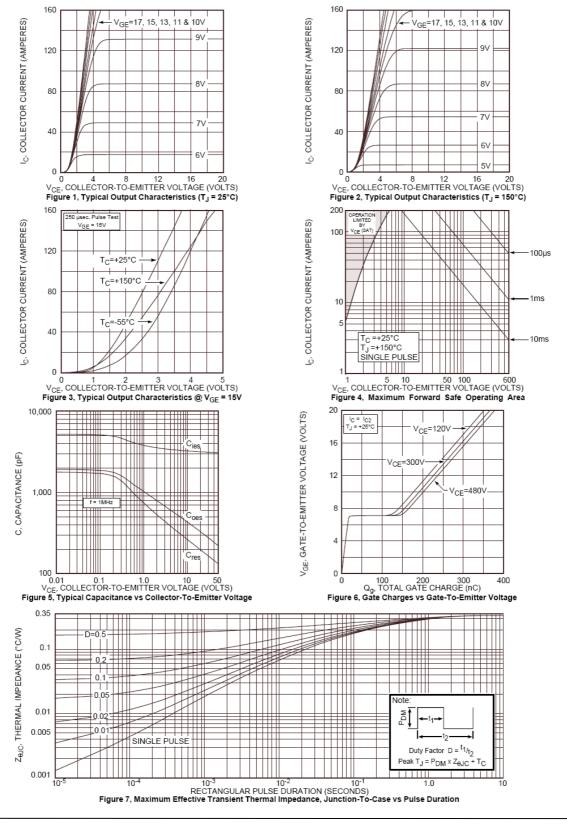
Symbol	Characteristic	<b>Test Conditions</b>		Min	Тур	Max	Unit
	Diode Forward Voltage	$I_F = 30A$			1.6	1.8	
$V_{\rm F}$		$I_F = 60A$			1.9		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.4		
I <sub>RM</sub>	Maximum Reverse Leakage Current	$V_{R} = 600V$	$T_j = 25^{\circ}C$			250	μA
IRM		$V_{R} = 600 V$	$T_{j} = 125^{\circ}C$			500	μл
C <sub>T</sub>	Junction Capacitance	$V_{R} = 200V$			44		pF
4	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt=100A/µs	$T_j = 25^{\circ}C$		23		
$t_{rr}$	Reverse Recovery Time		$T_i = 25^{\circ}C$		85		ns
		$T_{i} = 125^{\circ}C$		160			
I <sub>RRM</sub>	Maximum Reverse Recovery Current	$I_F = 30A$	$T_j = 25^{\circ}C$		4		А
IRRM	Waximum Reverse Recovery Current	$V_{\rm R} = 400 V$	$T_{i} = 125^{\circ}C$		8		Α
0	Powerse Posewary Charge	$di/dt = 200 A/\mu s$	$T_j = 25^{\circ}C$		130		nC
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		700		IIC
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 30A$ $V_R = 400V$ $di/dt = 1000A/\mu s$			70		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		1300		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current				30		Α

## Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case	IGBT			0.33		
		Diode			1.21	°C/W	
R <sub>thJA</sub>	Junction to Ambient (IGBT & Diode)				20		
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V	
$T_J, T_{STG}$	Storage Temperature Range		-55		150	°C	
T <sub>L</sub>	Max Lead Temp for Soldering:0.063" from case for 10 sec				300		
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m	
Wt	Package Weight			29.2		g	



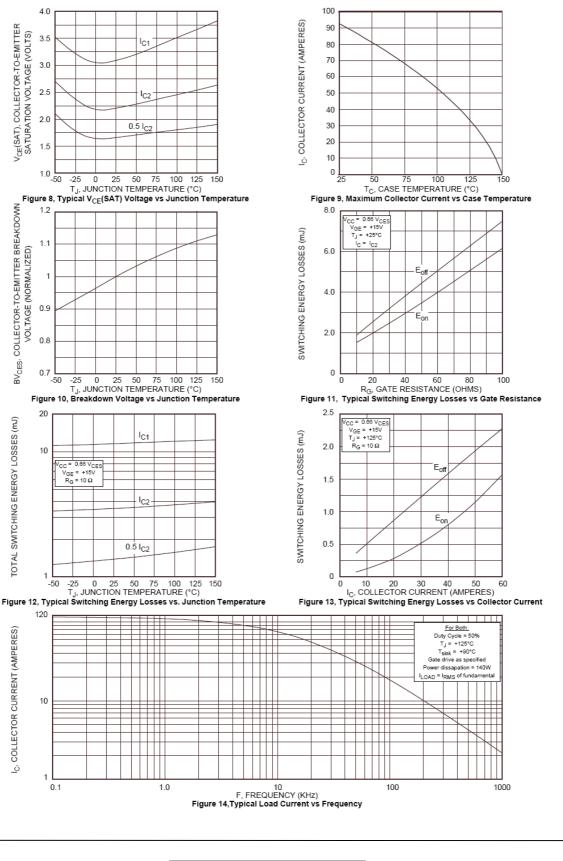
#### **Typical IGBT Performance Curve**



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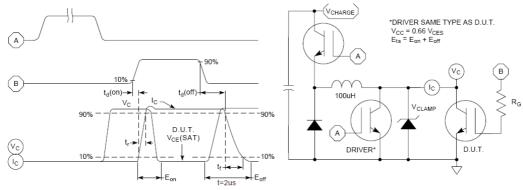


Figure 15, Switching Loss Test Circuit and Waveforms

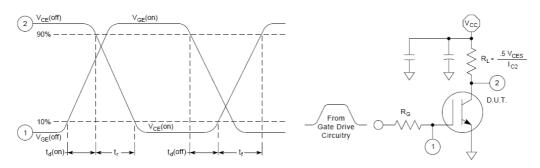
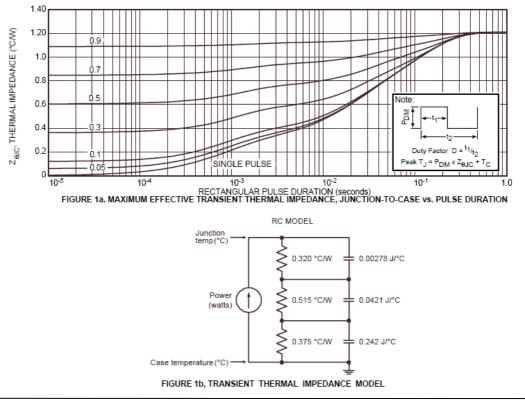


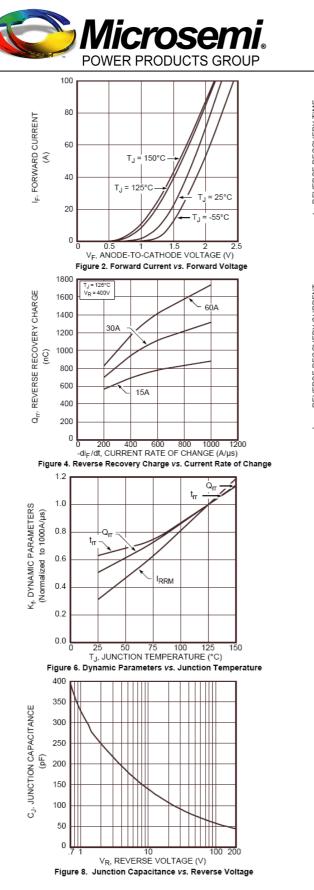
Figure 16, Resistive Switching Time Test Circuit and Waveforms

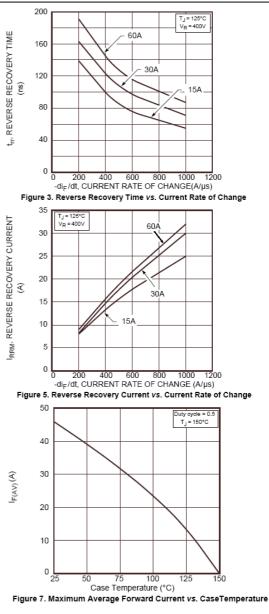


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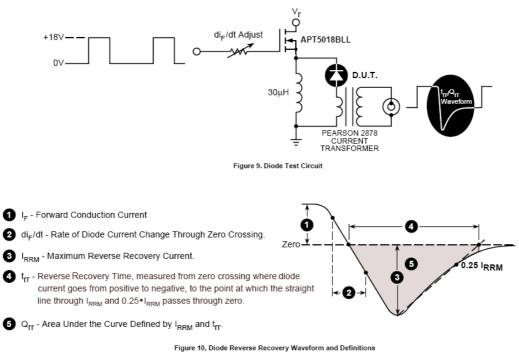


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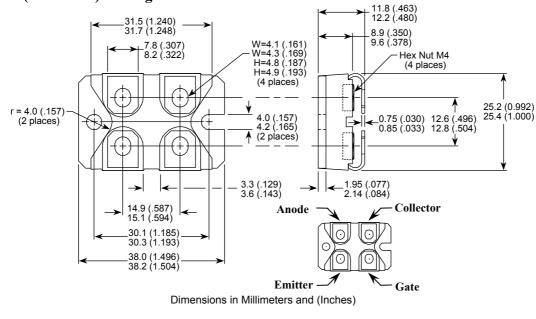
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## SOT-227 (ISOTOP<sup>®</sup>) Package Outline



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